### **ISO8200AQ**



# Galvanic isolated octal high side smart power solid state relay with SPI interface

Datasheet - Production data



#### **Features**

- V<sub>demag</sub> = V<sub>CC</sub> 45 V (per channel)
- $R_{DS(on)} = 0.120 \Omega$  (per channel)
- I<sub>OUT</sub> = 0.7 A (per channel)
- V<sub>CC</sub> = 45 V
- · SPI interface with daisy chaining
- 5 V and 3.3 V TTL/CMOS & µC compatible I/Os
- · Common output enable/disable pin
- Fast demagnetization of inductive loads
- · Reset function for IC outputs disable
- Very low supply current
- Undervoltage shutdown with auto restart and hysteresis
- Short-circuit protection
- Per-channel overtemperature protection
- Thermal independence of separate channels
- Case overtemperature protection
- · Loss of Ground and Supply protections
- Overvoltage protection (V<sub>CC</sub> clamping)
- Common OVT fault open drain output
- · Power GOOD open drain output
- High common mode transient immunity
- ESD protection
- Designed to meet IEC 61000-4-2, IEC 61000-4-4, IEC 61000-4-5 and IEC 61000-4-8
- UL1577 certified

### **Applications**

- Programmable logic control
- Industrial PC peripheral input/output
- Numerical control machines
- Drivers for all type of loads (resistive, capacitive, inductive)

### **Description**

The ISO8200AQ is a galvanic isolated 8-channel driver featuring a very low supply current. It contains 2 independent galvanic isolated voltage domains ( $V_{CC}$  and  $V_{DD}$  for the Process and Control Logic stages, respectively). The IC is intended for driving any kind of load with one side connected to ground.

The Control Logic Stage features an 8-bit Output Status Register (where the  $\mu$ C sets the status ON/OFF of the output channels in the Process Stage) and an 8-bit Fault Register (where the OVT faults of each channel are stored). The two stages communicate through the galvanic isolation channel by an ST proprietary protocol.

Active channel current limitation (OVL) combined with thermal shutdown (OVT), independent for each channel, protects the device against overload and overtemperature.

Additional embedded functions are: loss of ground protection,  $V_{CC}$  and  $V_{DD}$  UVLOs (with hysteresis), watchdog and  $V_{CC}$  Power GOOD.

An internal circuit provides an OR-wired not latched common ( $\overline{FAULT}$ ) indicator signaling the channel OVT. The ( $\overline{PGOOD}$ ) diagnostic pin is activated if V<sub>CC</sub> goes below the power good internal threshold. Both ( $\overline{FAULT}$ ) and ( $\overline{PGOOD}$ ) pins are open drain, active low, fault indication pins.

### **Contents**

1	Bloc	k diagram 6
2	Pin o	connection
3	Abso	olute maximum ratings9
4	Ther	mal data
5	Elec	trical characteristics11
6	Seria	al interface
	6.1	Functional description
	6.2	Serial data in (SDI)
	6.3	Serial data out (SDO)
	6.4	Serial data clock (CLK)
	6.5	Slave select (SS)
		6.5.1 Watchdog
		6.5.2 Output enable (OUT_EN)
	6.6	FAULT and PGOOD indications
	6.7	Truth table
		6.7.1 Junction overtemperature
7	Pow	er section
	7.1	Current limitation
	7.2	Thermal protection
8	Reve	erse polarity protection27
9	Reve	erse polarity on V <sub>DD</sub> 28
10	Dem	agnetization energy
11	Con	ventions
	11.1	Supply voltage and power output conventions

ISO8200AQ	Contents
-----------	----------

12			
13	Daisy chaining		1
14	Package information		2
	14.1 TFQFPN32 package information	ation 3:	2
15	Packing information		6
	15.1 TFQFPN32 packing informa	tion	6
	_	nethod concept	
	15.1.2 TFQFPN32 winding of	irection	7
	15.1.3 TFQFPN32 leader ar	d trailer	8
16	Ordering information		9
17	Revision history		9

List of tables ISO8200AQ

### List of tables

Table 1.	Pin description	7
Table 2.	Absolute maximum ratings	9
Table 3.	Thermal data	
Table 4.	Power section	11
Table 5.	Digital supply voltage	11
Table 6.	Diagnostic pin and output protection function	12
Table 7.	Power switching characteristics (V <sub>CC</sub> = 24 V; -40°C < T <sub>J</sub> < 125°C)	12
Table 8.	Logic inputs and output	15
Table 9.	Serial interface timings (V <sub>DD</sub> = 5 V; V <sub>CC</sub> = 24 V; -40°C < T <sub>J</sub> < 125°C)	15
Table 10.	Internal communication timings (V <sub>DD</sub> = 5 V; V <sub>CC</sub> = 24 V; -40°C < T <sub>J</sub> < 125°C)	16
Table 11.	Insulation and safety-related specifications	16
Table 12.	Insulation characteristics	16
Table 13.	Truth table	22
Table 14.	TFQFPN32 mechanical data	33
Table 15.	Tolerance of form and position	34
Table 16.	Ordering information	
Table 17	Document revision history	30



ISO8200AQ List of figures

# List of figures

-ıgure 1.	Block diagram	
igure 2.	Pin connection (top through view)	
igure 3.	RDS(on) measurement	
igure 4.	dV/dT definition	
igure 5.	td(ON)-td(OFF) definition	14
igure 6.	SPI mode diagram	18
igure 7.	SPI input timing diagram	19
igure 8.	SPI output timing diagram	19
igure 9.	Watchdog behavior	20
igure 10.	OUT_EN without effect on output	21
igure 11.	OUT_EN effective on output channel	21
igure 12.	Power GOOD pin behavior	22
Figure 13.	Thermal status update	23
igure 14.	Switching on resistive load	24
igure 15.	Switching on bulb lamp	24
igure 16.	Switching on light inductive load	
igure 17.	Switching on heavy inductive load	24
Figure 18.	Short-circuit during ON state	24
igure 19.	Switching on short-circuit	24
igure 20.	Thermal protection flowchart	25
igure 21.	Thermal protection and fault behavior (T <sub>JSD</sub> triggered before T <sub>CSD</sub> )	26
igure 22.	Thermal protection and fault behavior (T <sub>CSD</sub> triggered before T <sub>JSD</sub> )	26
igure 23.	Reverse polarity protection	27
igure 24.	V <sub>DD</sub> reverse polarity protection	
igure 25.	Single pulse demagnetization energy vs. load current (Typical values at TAMB = 125°C)	29
igure 26.	Supply voltage and power output conventions	29
igure 27.	Simplified thermal model of the process stage	
igure 28.	Example of daisy chaining connection	
igure 29.	TFQFPN32 outline	32
igure 30.	Package details	33
igure 31.	TFQFPN32 suggested footprint (measured in mm)	35
igure 32.	TFQFPN32 packing method concept	36
igure 33.	TFQFPN32 carrier tape	36
igure 34.	TFQFPN32 reel.	37
igure 35.	TFQFPN32 winding direction	37
Figure 36	TEOEPN32 leader and trailer	38



DS12812 Rev 4 5/40

Block diagram ISO8200AQ

# 1 Block diagram

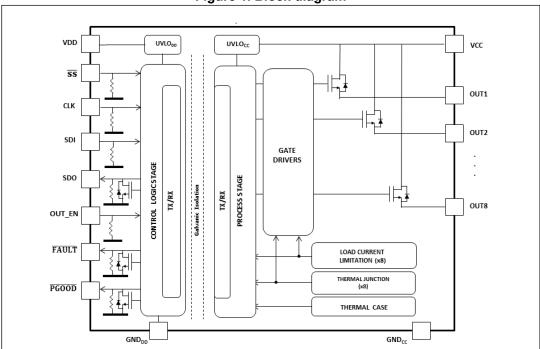


Figure 1. Block diagram

ISO8200AQ Pin connection

### 2 Pin connection

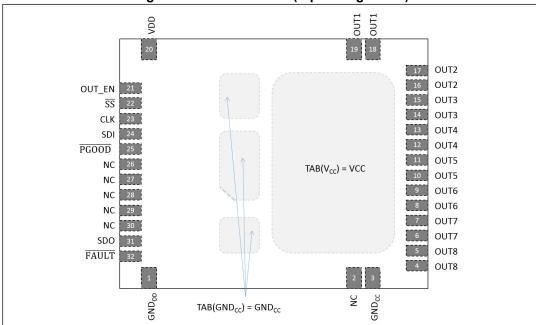


Figure 2. Pin connection (top through view)

Table 1. Pin description

Pin	Name	Description
1	GND <sub>DD</sub>	Input Control Logic Stage ground, negative logic supply
2	NC	Not connected
3	GND <sub>CC</sub>	Output power ground
4	OUT8	Channel 9 newer output
5	OUT8	Channel 8 power output
6	OUT7	Channel 7 newer output
7	OUT7	Channel 7 power output
8	OUT6	Channel 6 newer output
9	OUT6	Channel 6 power output
10	OUT5	Channel E newer output
11	OUT5	Channel 5 power output
12	OUT4	Channel 4 newer output
13	OUT4	Channel 4 power output
14	OUT3	Channel 2 newer output
15	OUT3	Channel 3 power output
16	OUT2	Channel 2 newer output
17	OUT2	Channel 2 power output

Pin connection ISO8200AQ

Table 1. Pin description (continued)

Pin	Name	Description
18	OUT1	Charried 4 management
19	OUT1	Channel 1 power output
20	V <sub>DD</sub>	Positive Control Logic Stage supply
21	OUT_EN	Output enable
22	SS	Chip select
23	CLK	Serial Clock Digital Input
24	SDI (MOSI)	SPI device Input
25	PGOOD	Power Good diagnostic pin - active low
26	NC	Not connected
27	NC	Not connected
28	NC	Not connected
29	NC	Not connected
30	NC	Not connected
31	SDO (MISO)	SPI device Output
32	FAULT	Common fault diagnostic pin - active low
TAB(V <sub>CC</sub> )	V <sub>CC</sub>	Exposed tab internally connected to $V_{\text{CC}}$ , positive Process Stage supply voltage
TAB(GND <sub>CC</sub> )	GND <sub>CC</sub>	Exposed tab internally connected to GNDcc (ground of Process Stage)

# 3 Absolute maximum ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Min.	Max.	Unit
V <sub>CC</sub>	Process Stage supply voltage	-0.3	+45	V
V <sub>DD</sub>	Control Logic Stage supply voltage	-0.3	+6.5	V
V <sub>IN</sub>	DC Input pins voltage (INx, SS, CLK, SDI, OUT_EN)	-0.3	+6.5	V
V <sub>FAULT</sub> , V <sub>PGOOD</sub>	FAULT and PGOOD pins voltage	-0.3	+6.5	V
I <sub>GNDdd</sub>	DC digital ground reverse current		-25	mA
I <sub>OUT</sub>	Channel Output Current (continuous)		Internally limited	Α
I <sub>GNDcc</sub>	DC power ground reverse current		-250	mA
I <sub>RX</sub>	Single channel reverse output current (from OUTX pins to $V_{CC}$ )		-5	Α
I <sub>RT</sub>	Total reverse output current (from OUTX pins to V <sub>CC</sub> ) @ TAMB 25°C		-12	Α
I <sub>IN</sub>	DC Input pins current (INx, SS, CLK, SDI, OUT_EN)	-10	+10	mA
I <sub>FAULT</sub> , I <sub>PGODD</sub>	FAULT and PGOOD pins current	-10	+10	mA
V <sub>ESD</sub>	Electrostatic discharge with Human Body Model (R = 1.5K $\Omega$ ; C = 100 pF)		2000	V
	Single pulse avalanche energy per channel not simultaneously @Tamb= 125 °C, I <sub>OUT</sub> = 0.5 A		1.8	
EAS	Single pulse avalanche energy per channel, all channels driven simultaneously @Tamb= 125 °C, I <sub>OUT</sub> = 0.5 A		0.35	J
P <sub>TOT</sub>	Power dissipation at T <sub>c</sub> = 25 °C		Internally limited <sup>(1)</sup>	W
TJ	Junction operating temperature		Internally limited <sup>(1)</sup>	°C
T <sub>STG</sub>	Storage temperature		-55 to 150	°C

Protection functions are intended to avoid IC damage in fault conditions and are not intended for continuous operation. Continuous or repetitive operation of protection functions may reduce the IC lifetime.



DS12812 Rev 4 9/40

Thermal data ISO8200AQ

### 4 Thermal data

Table 3. Thermal data

Symbol	Parameter	Max. value	Unit
R <sub>th j-case</sub>	Thermal resistance, junction-to-case <sup>(1)</sup>	1	
R <sub>th j-amb</sub>	R <sub>th j-amb</sub> Thermal resistance, junction-to-ambient <sup>(2)</sup>		°C/W
R <sub>th j-amb</sub>	Thermal resistance, junction-to-ambient <sup>(3)</sup>	15	

<sup>1.</sup> Rth between the die and the bottom case surface measured by cold plate as per JESD51.

<sup>2.</sup> JESD51-7.

<sup>3.</sup> IC mounted on the product evaluation board (FR4, 4 layers, 8 cm2 for each layer, copper thickness 35 mm).

### 5 Electrical characteristics

(10.5 V < V  $_{CC}$  < 36 V; -40 °C < T  $_{J}$  < 125 °C, unless otherwise specified.)

Table 4. Power section

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit	
V <sub>CC(THON)</sub>	V <sub>CC</sub> undervoltage turn-on threshold			9.5	10.5	V	
V <sub>CC(THOFF)</sub>	V <sub>CC</sub> undervoltage turn-off threshold		8	9		V	
V <sub>CC(HYS)</sub>	V <sub>CC</sub> undervoltage hysteresis		0.25	0.5		V	
V <sub>CCclamp</sub>	Clamp on VCC pin	Iclamp = 20 mA	45	50	52	V	
V <sub>CC(PGON)</sub>	V <sub>CC</sub> Power Good turn-on threshold	V <sub>DD</sub> = 3.3 V, VCC increasing		17.5	18.4	V	
V <sub>CC(PGOFF)</sub>	V <sub>CC</sub> Power Good turn-off threshold	V <sub>DD</sub> = 3.3 V, VCC decreasing	15.2	16.5		V	
V <sub>CC(PG-</sub>	V <sub>CC</sub> Power Good hysteresis			1		V	
P	ON state resistance	$I_{OUT} = 0.5 \text{ A}, T_{J} = 25 \text{ °C}$		0.12		Ω	
R <sub>DS(ON)</sub>		I <sub>OUT</sub> = 0.5 A, T <sub>J</sub> = 125 °C			0.24		
R <sub>PD</sub>	Output pull-down resistor			210		kΩ	
Icc	Power supply current	All channels in OFF state All channels in ON state		5 9		mA	
I <sub>LGND</sub>	Ground disconnection output current	V <sub>CC</sub> = VGND = 0 V V <sub>OUT</sub> = -24 V			500	μA	
V <sub>OUT(OFF)</sub>	OFF state output voltage	Channel OFF and I <sub>OUT</sub> = 0 A			1	V	
I <sub>OUT(OFF)</sub>	OFF state output current	Channel OFF and V <sub>OUT</sub> = 0 V			5	μΑ	

Table 5. Digital supply voltage

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
V <sub>DD</sub>	Operating voltage range		2.75		5.5	V
V <sub>DD(THON)</sub>	V <sub>DD</sub> undervoltage turn-on threshold		2.55		2.75	V
V <sub>DD(THOFF)</sub>	V <sub>DD</sub> undervoltage turn-off threshold		2.45		2.65	V
V <sub>DD(HYS)</sub>	V <sub>DD</sub> undervoltage hysteresis		0.04	0.1		V
I <sub>DD</sub>	V <sub>DD</sub> supply current	V <sub>DD</sub> = 5 V and SPI not transmitting		4.5	6	mA
		V <sub>DD</sub> = 3.3 V and SPI not transmitting		4.4	5.9	mA



Electrical characteristics ISO8200AQ

Table 6. Diagnostic pin and output protection function

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
V <sub>FAULT</sub>	FAULT pin open drain voltage output low	I <sub>FAULT</sub> = 5 mA			0.4	V
I <sub>LFAULT</sub>	FAULT output leakage current	V <sub>FAULT</sub> = 5 V			1	μΑ
V <sub>PGOOD</sub>	PGOOD pin open drain voltage output low	I <sub>PGOOD</sub> = 5 mA			0.4	V
I <sub>LPGOOD</sub>	PGOOD output leakage current	V <sub>PGOOD</sub> = 5 V			1	μA
I <sub>PEAK</sub>	Maximum DC output current before limitation	V <sub>CC</sub> = 24 V		1.6		Α
I <sub>LIM</sub>	Short-circuit current limitation	$R_{LOAD} = 0 \Omega$	0.7	1.3	1.9	Α
Hyst	ILIM tracking limits			0.3		Α
T <sub>JSD</sub>	Junction shutdown temperature		150	170		°C
T <sub>JR</sub>	Junction reset temperature			150		°C
T <sub>HIST</sub>	Junction thermal hysteresis			20		°C
T <sub>CSD</sub>	Case shutdown temperature		115	130	145	°C
T <sub>CR</sub>	Case reset temperature			110		°C
T <sub>CHYST</sub>	Case thermal hysteresis			20		°C
V <sub>DEMAG</sub>	Output voltage at turn-off	I <sub>OUT</sub> = 0.5 A; ILOAD >= 1 mH	V <sub>CC</sub> -45	V <sub>CC</sub> -50	V <sub>CC</sub> -52	V

Table 7. Power switching characteristics ( $V_{CC}$  = 24 V; -40°C <  $T_J$  < 125°C)

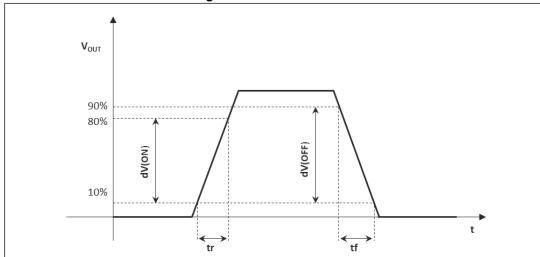
Symbol	Parameter Test conditions		Min.	Тур.	Max.	Unit
dV/dt(ON)	Turn-on voltage slope	$I_{OUT}$ = 0.5 A, resistive load 48 Ω		5.6		V/µs
dV/dt(OFF)	Turn-off voltage slope	$I_{OUT}$ = 0.5 A, resistive load 48 Ω		2.81		V/µs
td(ON)	Turn-on delay time (see Figure 5)	$I_{OUT}$ = 0.5 A, resistive load 48 $\Omega$		17	22	μs
td(OFF)	Turn-off delay time (see Figure 5)	$I_{OUT}$ = 0.5 A, resistive load 48 $\Omega$		22	40	μs
tf	Fall time (see Figure 4)	$I_{OUT}$ = 0.5 A, resistive load 48 Ω		5		μs
tr	Rise time (see Figure 4)	$I_{OUT}$ = 0.5 A, resistive load 48 Ω		5		μs
t <sub>w(OUT_EN)</sub>	OUT_EN pulse width (see Figure 10, 11)	$I_{OUT}$ = 0.5 A, resistive load 48 $\Omega$	150			ns
t <sub>p(OUT_EN)</sub>	OUT_EN propagation delay (see <i>Figure 10</i> , <i>11</i> )	$I_{OUT}$ = 0.5 A, resistive load 48 $\Omega$		22	40	μs

TAB Vcc

VRDS(oN)

Figure 3. RDS(on) measurement





Electrical characteristics ISO8200AQ

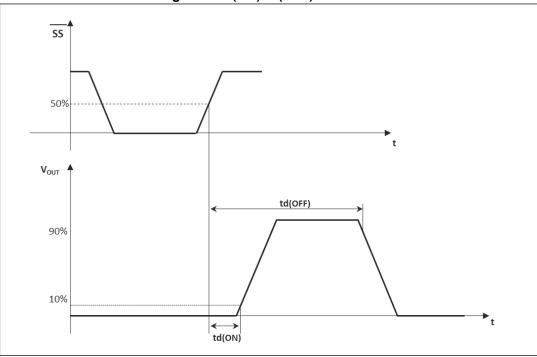


Figure 5. td(ON)-td(OFF) definition

Table 8. Logic inputs and output

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
V <sub>IL</sub>	SS, CLK, SDI and OUT_EN low level voltage		-0.3		0.3 x V <sub>DD</sub>	٧
V <sub>IH</sub>	SS, CLK, SDI and OUT_EN high level voltage		0.7 x V <sub>DD</sub>		V <sub>DD</sub> +0.3	V
V <sub>I(HYST)</sub>	SS, CLK, SDI and OUT_EN hysteresis	V <sub>DD</sub> = 5 V		100		mV
I <sub>IN</sub>	SS, CLK, SDI and OUT_EN current	V <sub>IN</sub> = 5 V	10			μA
V <sub>SDOH</sub>	SDO high level voltage	I <sub>SDO</sub> = -1 mA	V <sub>DD</sub> -0.2			V
V <sub>SDOL</sub>	SDO low level voltage	I <sub>SDO</sub> = +2 mA			0.2	V

Table 9. Serial interface timings (V<sub>DD</sub> = 5 V; V<sub>CC</sub> = 24 V; -40°C < T<sub>J</sub> < 125°C)

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
fCLK	SPI clock frequency				20	MHz
T <sub>CLK</sub>	SPI clock period		50			ns
tr(CLK) tf(CLK)	SPI clock rise/fall time (see Figure 7, 8)				5	ns
tsu(SS)	SS setup time (see Figure 7, 8)		80			ns
th(SS)	SS hold time (see Figure 7, 8)		80			ns
tc(SS)	SS disable time (see Figure 7, 8)		20			μs
tw(CLK)	CLK high time (see Figure 7, 8)		15			ns
tsu(SDI)	Data input setup time (see <i>Figure 7</i> , <i>8</i> )		6			ns
th(SDI)	Data input hold time (see <i>Figure 7</i> , <i>8</i> )		6			ns
ta(SDO)	Data output access time (see <i>Figure 7</i> , <i>8</i> )	   R <sub>PULL-DOWN</sub> = 300 Ω			25	ns
tdis(SDO)	Data output disable time (see Figure 7, 8)	C <sub>LOAD</sub> = 50 pF			20	ns
tv(SDO)	Data output valid time (see Figure 7, 8)				20	ns
t	Jitter on single channel $t_{CYCLE(SS)}$ = 20 μs				6	116
t <sub>JITTER</sub>	Jitter on single channel t <sub>CYCLE(SS)</sub> < 20 μs				20	μs



Electrical characteristics ISO8200AQ

### Table 10. Internal communication timings (V<sub>DD</sub> = 5 V; V<sub>CC</sub> = 24 V; -40°C < T<sub>J</sub> < 125°C)

Symbol	Parameter	Test condition	Min.	Тур.	Max.	Unit
f <sub>refresh</sub>	Refresh delay			15		kHz
t <sub>WD</sub>	Watchdog time		272	320	400	μs

#### Table 11. Insulation and safety-related specifications

Symbol	Parameter	Test conditions	Value	Unit
CLR	Clearance (minimum external air gap )	Measured from input terminals to output terminals, shortest distance through air	3.3	mm
CPG	Creepage (minimum external tracking)	Measured from input terminals to output terminals, shortest distance path along body	3.3	mm
СТІ	Comparative tracking index (tracking resistance)	DIN IEC 112/VDE 0303 part 1	≥600	V
	Isolation group	Material group (DIN VDE 0110, 1/89, Table 1)	I	-

#### **Table 12. Insulation characteristics**

Symbol	Parameter	Test condition	Value	Unit							
IEC 60747	EC 60747-5-5										
V <sub>IORM</sub>	Maximum working isolation	-	937	V <sub>PEAK</sub>							
		Method a, type test,  V <sub>PR</sub> = V <sub>IORM</sub> x 1.6, tm = 10s  partial discharge < 5 pC	1500	$V_{PEAK}$							
V <sub>PR</sub>	Input-to-output test voltage	Method b, 100% production test, V <sub>PR</sub> = V <sub>IORM</sub> x 1.875, tm = 1s partial discharge < 5 pC	1758	V <sub>PEAK</sub>							
V <sub>IOTM</sub>	Transient overvoltage	Type test; t <sub>ini</sub> = 60 s	4245	V <sub>PEAK</sub>							
V <sub>IOSM</sub>	Maximum surge insulation voltage	Type test	4245	V <sub>PEAK</sub>							
R <sub>IO</sub>	Insulation resistance	V <sub>IO</sub> = 500 V at ts	>10 <sup>9</sup>	Ω							
UL1577											
V <sub>ISO</sub>	Insulation withstand voltage	1 min. type test	2500/3536	$V_{rms}/V_{PEAK}$							
V <sub>ISO</sub> test	Insulation withstand test	1 sec. 100% production	3000/4245	V <sub>rms</sub> /V <sub>PEAK</sub>							

16/40 DS12812 Rev 4

ISO8200AQ Serial interface

#### 6 Serial interface

#### 6.1 Functional description

An integrated SPI peripheral permits to have a fast communication interface between external microcontroller and IC purposing, both to drive the Power Stage outputs and check the per-channel OVT diagnostic information of the device. Daisy chaining is allowed.

It follows the timing requirement established by the synchronous serial communication standard and works up to 20 MHz communication speed.

The communication implemented expects 8-bit data communication; the frame sent by the microcontroller contains only the status of the channels (ON or OFF), while the frame received by the microcontroller contains the information regarding channel fault condition (bit "0" related to a channel running represents normal operation, whereas a bit 1 represents a fault condition).

#### **SDI frame**

MSB							LSB
IN7	IN6	IN5	IN4	IN3	IN2	IN1	IN0

#### **SDO frame**

	MSB							LSB
Ī	F7	F6	F5	F4	F3	F2	F1	F0

### 6.2 Serial data in (SDI)

This pin is the IC input of the serial command frame (MOSI). SDI is reading on CLK rising edges and, thus, the microcontroller must change SDI state during the CLK falling edges.

SDI pin is tri-stated when one of the following conditions is met:

- SS signal is high.
- OUT EN pin is active.

The bits sent through the SDI line are shifted in the internal Output Status Register. In daisy chaining communication the microcontroller maintains the  $\overline{SS}$  low after the 8th bit to allow the shift of the Output Status Register to the SDO line. The bits in the Output Status Register are frozen by the internal logic when the  $\overline{SS}$  goes high.

### 6.3 Serial data out (SDO)

This pin is the IC output of the serial fault frame (MISO). The information on SDO is updated on CLK falling edges; the microcontroller reads SDO frame on CLK rising edges as established by standard. At communication startup, when  $\overline{SS}$  falling edge is coming, just the first bit of the frame is available.

SDO pin is tri-stated when SS signal is high.

Serial interface ISO8200AQ

In daisy chaining communication and OUT\_EN driven high, the SDO line transfers the content of the internal Output Status Register after the 8th CLK pulse.

### 6.4 Serial data clock (CLK)

The CLK line is the IC input clock for serial data sampling. SDO is updated on CLK falling edges, and then it must be sampled on the rising edge. The SDI line is sampled on SCK rising edges.

When the SS signal is high (slave not selected), the microcontroller should drive the CLK low (settings for MCU SPI port are CPHA = 0 and CPOL = 0).

### 6.5 Slave select $(\overline{SS})$

Slave select  $\overline{SS}$  signal is used to enable the ISO8200AQ serial communication shift register. Data is flushed in through the SDI pin and out from the SDO pin only when the  $\overline{SS}$  pin is low. On the  $\overline{SS}$  pin falling edge the Fault Register (containing IC fault conditions) is frozen, so any changing on the channel status is latched until the next  $\overline{SS}$  falling edge event, the SDO is enabled and at the same time the internal refresh is disabled too. On the  $\overline{SS}$  pin rising edge event the 8 bits in the Output Status Register are frozen and the outputs of the Process Stage are driven accordingly. If more than 8 bits are flushed into the IC, only the last 8 are evaluated, the other ones are flushed out from the SDO pin after fault condition bits; this way a proper communication is granted also in a daisy chain configuration.

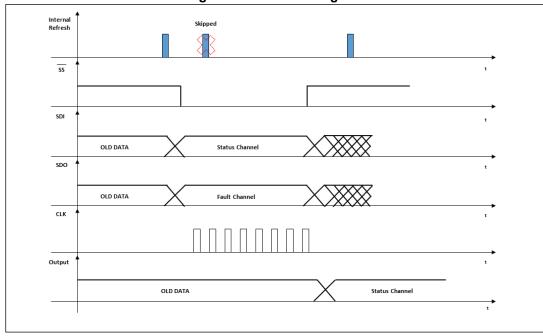


Figure 6. SPI mode diagram

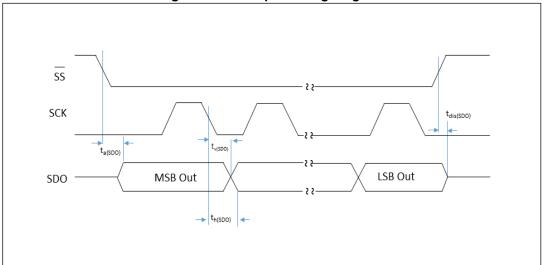
18/40 DS12812 Rev 4

ISO8200AQ Serial interface

SCK  $t_{cycla(\overline{c}\overline{s})}$  SCK  $t_{w(CLK)}$  SDI MSB In  $t_{cycla(\overline{c}\overline{s})}$   $t_{w(CLK)}$   $t_{w(CLK)}$   $t_{w(CLK)}$   $t_{w(CLK)}$   $t_{w(CLK)}$ 

Figure 7. SPI input timing diagram





Serial interface ISO8200AQ

#### 6.5.1 Watchdog

The IC is composed of two chips (Logic Stage and Process Stage) supplied by two independent and galvanic isolated sources ( $V_{DD}/GND_{DD}$  and  $V_{CC}/GND_{CC}$  pins, respectively).

The IC provides a watchdog function in order to guarantee a safe condition of the Process Stage when  $V_{DD}$  (or  $GND_{DD}$ ) supply voltage is missing. At the end of each SPI communication the channel status register is transferred to the Process Stage that both resets an internal timeout counter and turns ON/OFF the outputs accordingly. If the Logic Stage does not update the output status within tWD, all the outputs of the Process Stage are disabled until a new update request is received (this also happens if  $\overline{SS}$  stays low for a time longer than  $t_{WD}$ ).

Independently of the SPI communication, the Logic Stage chip periodically sends a refresh signal to the Process Stage chip. The refresh signal is also considered a valid update signal to reset the timeout counter on the Process Stage, so the isolated side watchdog does not protect the system from a failure of the host controller (e.g. MCU freezing).

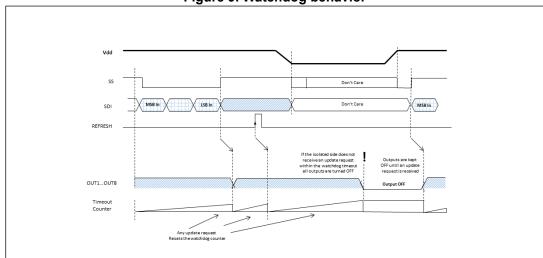


Figure 9. Watchdog behavior

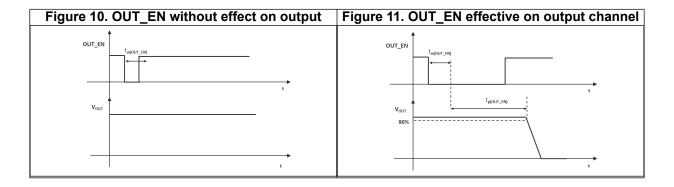
#### 6.5.2 Output enable (OUT\_EN)

This pin provides a fast way to disable all the outputs simultaneously. When the *OUT\_EN* pin is driven low for at least tw (OUT\_EN), all eight outputs are disabled. This timing execution is compatible with an external reset push from the operator and/or safety requirements.

Note that the OUT\_EN signal acts as a reset for the internal data register driving the output switches: when the OUT\_EN is low, SDO is pulled down and the output stage is forced OFF. To re-enable SDO it is necessary to raise the *OUT\_EN* pin; to enable back the output stage it is then necessary to raise the *OUT\_EN* pin and send the desired output configuration by an SPI command.

20/40 DS12812 Rev 4

ISO8200AQ Serial interface



#### 6.6 FAULT and PGOOD indications

The FAULT pin is an active low open drain output indicating fault conditions. This pin is activated when at least one of the following conditions occurs:

- Junction overtemperature (TJX >TJSD) of one or more channels of the Process Stage.
   The MISO signal can be used to detect which channels are in thermal fault (per-channel OVT diagnostic);
- No module-8 SPI communication (the number of bits sent through the SDI is not a multiple of 8);
- Internal communication error. In fact, the IC is able to identify (and report to the microcontroller) if any error in the data transmission between isolation happened. When it should happen, the output stage maintains the previous ON/OFF status.

The  $\overline{PGOOD}$  pin is an active low open drain output indicating if the supply voltage of the Process Stage chip is lower than the internal threshold (see *Figure 12*).

Note: When  $\overline{SS}$  signal is low the transmission between Control Logic Stage and Process Stage is inhibited and the status of  $\overline{PGOOD}$  is not refreshed ( $\overline{PGOOD}$  refresh time < 120 us).

Serial interface ISO8200AQ

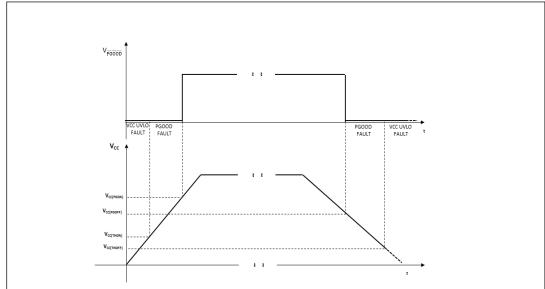


Figure 12. Power GOOD pin behavior

### 6.7 Truth table

Table 13. Truth table

14010 101 114111 44010							
Condition	Status register BIT <sub>x</sub>	OUT <sub>x</sub>	Fault register BIT <sub>x</sub>	FAULT	PGOOD		
Normal operation	1	ON	0	H (not active)	H (not active)		
Normal operation	0	OFF	0	TT (HOL ACTIVE)	TT (Hot active)		
Thermal Junction	1	OFF	1	L (active)	Don't care		
(T <sub>JX</sub> > T <sub>JSD</sub> )	0	OFF	1	H (not active)	Don't care		
Thermal Case T <sub>C</sub> > T <sub>CSD</sub>	S	See Figure 2	0	Don't care	Don't care		
V <sub>CC</sub> UVLO FAULT	0	OFF	X	X	L (active)		
(Figure 12)	1	OFF	^	^	L (active)		
POWER GOOD FAULT	1	ON	Don't care	Don't care	L (activo)		
(Figure 12)	0	OFF	Don't care	Dont care	L (active)		
V <sub>DD</sub> UVLO (Watchdog)	х	OFF	х	H (not active)	H (not active)		
SPI FAULT (module-8 violation)	х	Х	Don't care	L (active)	Don't care		
Internal communication error	Х	Х	Х	L (active)	Don't care		

x: maintain the previous condition.



ISO8200AQ Serial interface

#### 6.7.1 Junction overtemperature

The thermal status of the device is updated during each transmission sequence between the two isolated stages.

When  $\overline{SS}$  is low the communication between the two stages is disabled. In this case the thermal status of the device cannot be updated and the  $\overline{FAULT}$  indication may be different to the actual status. In any case the thermal protections of the channel outputs in the Process Stage are always operative.

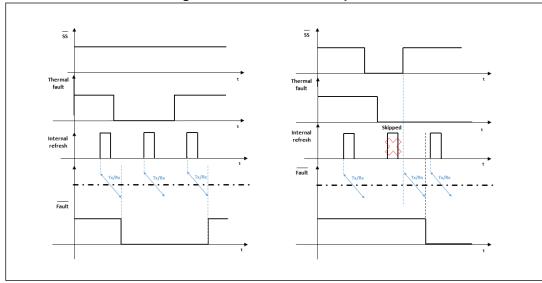


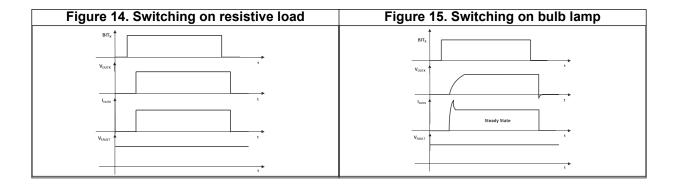
Figure 13. Thermal status update

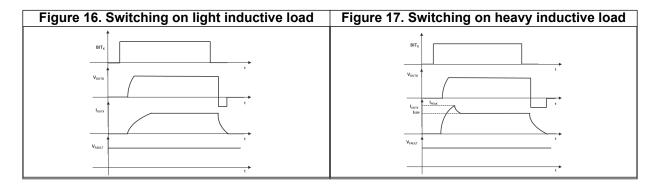
Power section ISO8200AQ

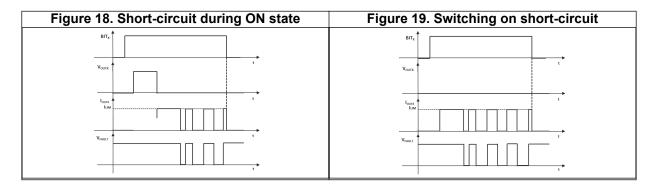
### 7 Power section

#### 7.1 Current limitation

The current limitation process is activated when the current sense connected on the output stage measures a current value higher than a fixed threshold. When this condition is verified the gate voltage is modulated to avoid output current increasing over the limitation value. The following figures (where  $BIT_X$  is intended as  $X^{TH}$  bit of the Output Status Register) show typical output current waveforms with different load conditions.







24/40 DS12812 Rev 4

ISO8200AQ Power section

### 7.2 Thermal protection

The device is protected against overheating due to overload conditions. During driving period, if the output is overloaded, the device suffers two different thermal stresses, the first one related to the junction, and the second related to the case.

The two faults have different trigger thresholds: the junction protection threshold ( $T_{JSD}$ ) is higher than that of the case protection ( $T_{CSD}$ ); generally the first protection that is activated in thermal stress conditions is the junction thermal shutdown. The output is turned off when the temperature is higher than the related threshold and turned back on when it goes below the reset threshold ( $T_{JR}$ ). This behavior continues until the fault on the output is present.

If the thermal protection is active and the temperature of the package increases over the fixed case protection threshold, the case protection is activated and the output is switched off and back on when the junction temperature of each channel in fault and case temperature are below the respective reset thresholds.

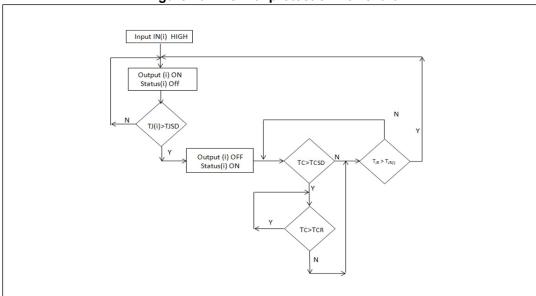


Figure 20. Thermal protection flowchart

25/40

Power section ISO8200AQ

Tous Test

Tax

Tsx

Tsx

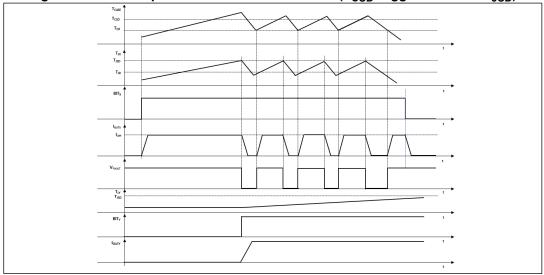
Tsx

Tsx

Vraux

Figure 21. Thermal protection and fault behavior ( $T_{JSD}$  triggered before  $T_{CSD}$ )





### 8 Reverse polarity protection

Reverse polarity protection can be implemented on board using two different solutions:

- 1. Placing a resistor (R<sub>GND</sub>) between IC GND pin and load GND
- 2. Placing a diode in parallel to a resistor between IC GND pin and load GND

If option 1 is selected, the minimum resistance value has to be selected according to the following equation:

#### **Equation 1**

$$R_{GND} \ge V_{CC}/I_{GNDcc}$$

where  $I_{GNDcc}$  is the DC reverse ground pin current and can be found in Section 3: Absolute maximum ratings on page 9 of this datasheet.

Power dissipated by R<sub>GND</sub> during reverse polarity situation is:

#### **Equation 2**

$$P_D = (V_{CC})^2 / R_{GND}$$

If option 2 is selected, the diode has to be chosen by taking into account VRRM >  $|V_{CC}|$  and its power dissipation capability:

#### **Equation 3**

$$P_D \ge I_S * V_F$$

Note:

In normal operation (no reverse polarity), there is a voltage drop ( $\Delta V$ ) between GND of the device and GND of the system. Using option 1,  $\Delta V$  = Rgnd \* Icc. Using option 2,  $\Delta V$  = VF@(IF).

+Vdd +Vcc

Inputi

GNDdd

GNDcc

RGND

Diode

Load

Figure 23. Reverse polarity protection

Note:

Input(i) is intended as any input pin on logic side.

This schematic can be used with any type of load.

57

DS12812 Rev 4 27/40

### 9 Reverse polarity on V<sub>DD</sub>

The reverse polarity on  $V_{DD}$  can be implemented on board by placing a diode between the  $\mathsf{GND}_{DD}$  pin and  $\mathsf{GND}$  digital ground.

The diode has to be chosen by taking into account VRRM  $>|V_{DD}|$  and its power dissipation capability:

#### **Equation 4**

 $P_D \ge I_{DD} * V_F$ 

Note:

In normal operation (no reverse polarity), there is a voltage drop ( $\Delta V = VF@(Idd)$ ) between  $GND_{DD}$  of the device and digital ground of the system. In order to guarantee to proper triggering of the input signal,  $\Delta V(max.)$  must result lower than  $V_{IH(MIN)}$ .

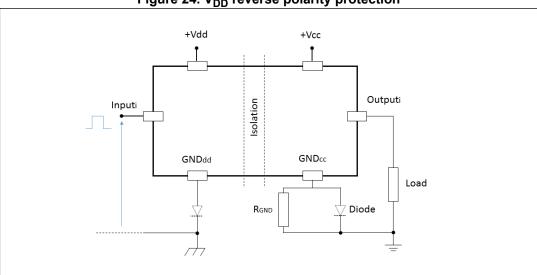


Figure 24.  $V_{DD}$  reverse polarity protection

Note:

Input(i) is intended as any input pin on logic side.

### 10 Demagnetization energy

Figure 25. Single pulse demagnetization energy vs. load current (Typical values at TAMB = 125°C)

### 11 Conventions

### 11.1 Supply voltage and power output conventions

Figure 26 shows all conventions used in this document for voltage and current usage.

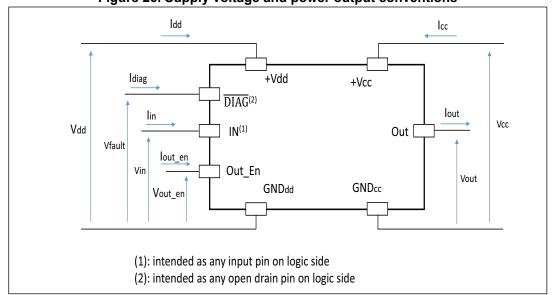


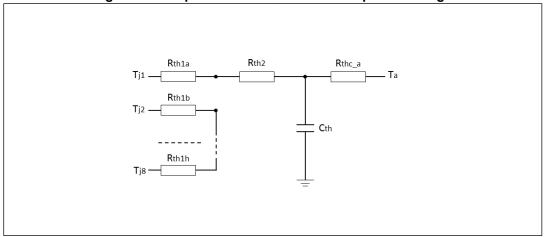
Figure 26. Supply voltage and power output conventions

Thermal information ISO8200AQ

### 12 Thermal information

### 12.1 Thermal impedance

Figure 27. Simplified thermal model of the process stage



ISO8200AQ Daisy chaining

## 13 Daisy chaining

ISO8200AQ can be daisy chained by connecting the serial data output (SDO) of one device to the digital input (SDI) of the following device in the chain (see *Figure 28*).

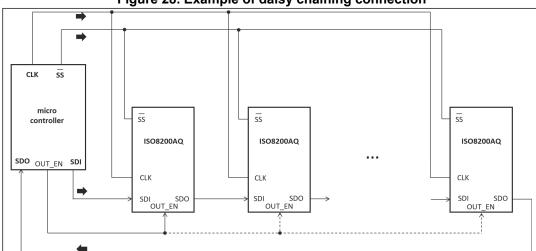


Figure 28. Example of daisy chaining connection

Package information ISO8200AQ

### 14 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: <a href="https://www.st.com">www.st.com</a>. ECOPACK<sup>®</sup> is an ST trademark.

### 14.1 TFQFPN32 package information

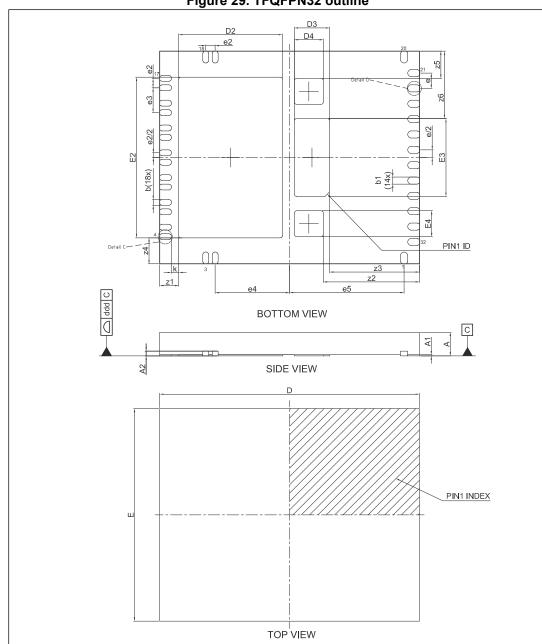


Figure 29. TFQFPN32 outline

ISO8200AQ **Package information** 

Section A-Anot in scale A1 <u>6</u> SEATING PLANE Detail D Detail C not in scale not in scale b b1 plating 5

Figure 30. Package details

Table 14. TFQFPN32 mechanical data

Dim	mm					
Dilli	Min.	Тур.	Max.			
A	0.95	1.00	1.05			
A1	0		0.05			
A2		0.20 REF				
b <sup>(1)</sup>	0.20	0.25	0.30			
b1 <sup>(1)</sup>	0.25	0.30	0.35			
D	10.90	11.0	11.10			

Package information ISO8200AQ

Table 14. TFQFPN32 mechanical data (continued)

Dive		mm	
Dim	Min.	Тур.	Max.
E <sup>(1)</sup>	8.90	9.00	9.10
D2	4.30	4.40	4.50
E2	6.70	6.80	6.90
D3	1.40	1.50	1.60
E3	3.20	3.30	3.40
D4	1.13	1.23	1.33
E4	1.00	1.10	1.20
е		0.65	
e2		0.40	
e3		1.05	
e4		3.15	
e5		4.85	
k	0	0.30	
z1		0.80	
z2		4.07	
z3		3.80	
z4		1.10	
z5		1.15	
z6		2.85	
L <sup>(1)</sup>	0.45	0.50	0.55

<sup>1.</sup> Dimensions "b" and "L" are measured at terminal plating surface.

Table 15. Rev 4

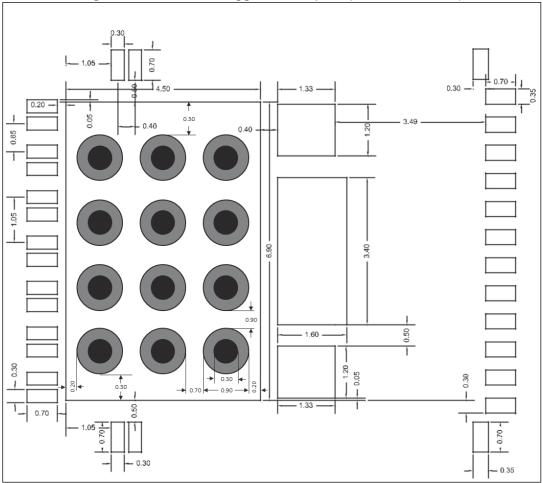
Symbol	Tolerance of form and position	Definition	Notes
aaa	0.15	The bilateral profile tolerance that controls the position of the plastic body sides. The centers of the profile zones are defined by the basic dimensions D and E.	
bbb	0.10	The tolerance that controls the position of the entire terminal pattern with respect to datum's A and B. The center of the tolerance zone for each terminal is defined by the basic dimension "e" as related to datum's A and B.	
ccc	0.10	The tolerance located parallel to the seating plane in which the top surface of the package must be located.	

34/40 DS12812 Rev 4

Table 15. Rev 4 (continued)

Symbol	Tolerance of form and position	Definition	Notes
ddd	0.08	The tolerance that controls the position of the terminals to each other. The centers of the profile zones are defined by basic dimension "e".	This tolerance is normally compounded with tolerance zone defined by bbb.
eee	0.08	The unilateral tolerance located above the seating plane where in the bottom surface of all terminals must be located.	This tolerance is commonly known as the "coplanarity" of the package terminals.
fff	0.10	The tolerance that controls the position of the exposed metal heat feature. The center of the tolerance zone will be datum's defined by the centerlines of the package body.	
REF	-	-	No tolerance for A2

Figure 31. TFQFPN32 suggested footprint (measured in mm)



**Packing information** ISO8200AQ

#### **Packing information** 15

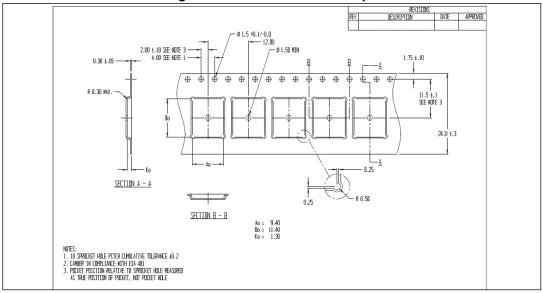
#### 15.1 **TFQFPN32** packing information

#### 15.1.1 **TFQFPN32** packing method concept

Packing Concept - Tape and Reel 13" in Dry Packing Humidity Desiccant Indicator Card Bag Bulk Label Plastic Reel Circular sprocket holes opposite the label side of reel Protective band Cover tape Inner Box Carrier tape **Enlongated** 

Figure 32. TFQFPN32 packing method concept





Reel – 330 mm diameter x 101 mm hub x 24 mm width.

36/40 DS12812 Rev 4 ISO8200AQ **Packing information** 

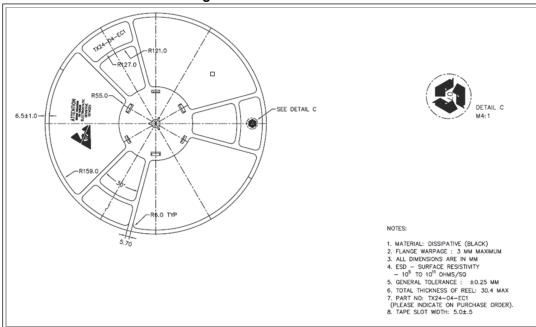


Figure 34. TFQFPN32 reel

#### **TFQFPN32** winding direction 15.1.2

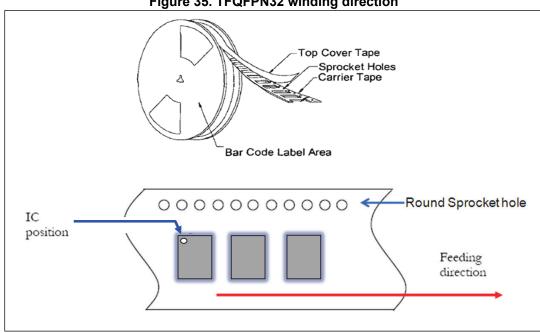
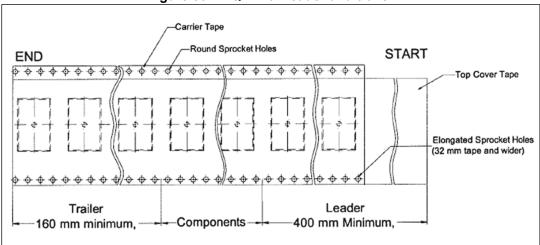


Figure 35. TFQFPN32 winding direction

Packing information ISO8200AQ

#### 15.1.3 TFQFPN32 leader and trailer

Figure 36. TFQFPN32 leader and trailer



Note: Leader and trailer length as per EAI-481 specification.

577

# 16 Ordering information

**Table 16. Ordering information** 

Part number	Package	Packaging
ISO8200AQ	TFQFPN32	Tube
ISO8200AQTR	TFQFPN32	Tape and reel

# 17 Revision history

Table 17. Document revision history

Date	Revision	Changes
31-Oct-2018	1	Initial release.
3-Dec-2018	2	Updated Figure 1 and Figure 28, amended Table 8
2-Jun-2019	3	Features updated. <i>Table 1</i> & <i>Table 2</i> modified. <i>Figure</i> replaced. Small changes to the text.
23-Apr-2020	4	Table 12 and 14 updated. Figure 29 replaced and Table 15 added.

#### IMPORTANT NOTICE - PLEASE READ CAREFULLY

STMicroelectronics NV and its subsidiaries ("ST") reserve the right to make changes, corrections, enhancements, modifications, and improvements to ST products and/or to this document at any time without notice. Purchasers should obtain the latest relevant information on ST products before placing orders. ST products are sold pursuant to ST's terms and conditions of sale in place at the time of order acknowledgement.

Purchasers are solely responsible for the choice, selection, and use of ST products and ST assumes no liability for application assistance or the design of Purchasers' products.

No license, express or implied, to any intellectual property right is granted by ST herein.

Resale of ST products with provisions different from the information set forth herein shall void any warranty granted by ST for such product.

ST and the ST logo are trademarks of ST. All other product or service names are the property of their respective owners.

Information in this document supersedes and replaces information previously supplied in any prior versions of this document.

© 2020 STMicroelectronics – All rights reserved

40/40 DS12812 Rev 4

### **X-ON Electronics**

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Power Switch ICs - Power Distribution category:

Click to view products by STMicroelectronics manufacturer:

Other Similar products are found below:

TLE6232GP NCP45520IMNTWG-L VND5E004ATR-E FPF1018 DS1222 NCV380HMUAJAATBG SZNCP3712ASNT3G

NCP45520IMNTWG-H VND5004ATR-E AP22811BW5-7 SLG5NT1437VTR SZNCP3712ASNT1G DML1008LDS-7 TS13011-QFNR

VND7012AYTR NCV459MNWTBG NCP4545IMNTWG-L NCV8412ASTT1G NCV8412ASTT3G FPF2260ATMX SLG5NT1765V

SLG5NT1757V NCP45780IMN24RTWG AP2151DMPG-13 AP2151AMP-13 NCP45540IMNTWG-L TPS2022P FPF2495BUCX

NCP45650IMNTWG NCV8412ADDR2G DK5V100R20S BTS7020-2EPA BTT6100-2ERA BTS71220-4ESA DK5V100R15M

WS3220C9-9/TR AW32405CSR BTT6030-2ERA TLE75602-ESH BTS5200-4EKA DK5V150R25M DK5V45R25 DK5V100R25S

AW35206FOR BTS7120-2EPA TLE75008-ESD BTS7040-1EPA BTT6030-1ERA DK5V60R10S DK5V45R25S